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MCH6613

Power MOSFET

30V, 0.35A, 3.7Ω –30V, –0.2A, 10.4Ω , Complementary Dual MCPH6

ON Semiconductor®

<http://onsemi.com>

Features

- The MCH6613 incorporates two elements in the same package which are N-channel and P-channel low ON resistance and high-speed switching MOSFETs, thereby enabling high-density mounting
 - Excellent ON-resistance characteristic
 - 1.5V drive

Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | N-channel | P-channel | Unit |
|-----------------------------|------------------|---|-------------|-----------|------|
| Drain to Source Voltage | V _{DSS} | | 30 | -30 | V |
| Gate to Source Voltage | V _{GSS} | | ±10 | ±10 | V |
| Drain Current (DC) | I _D | | 0.35 | -0.2 | A |
| Drain Current (Pulse) | I _{DP} | PW≤10μs, duty cycle≤1% | 1.4 | -0.8 | A |
| Allowable Power Dissipation | P _D | When mounted on ceramic substrate (900mm ² ×0.8mm) 1unit | 0.8 | | W |
| Channel Temperature | T _{ch} | | 150 | | °C |
| Storage Temperature | T _{stg} | | -55 to +150 | | °C |

This product is designed to “ESD immunity < 200V*”, so please take care when handling.

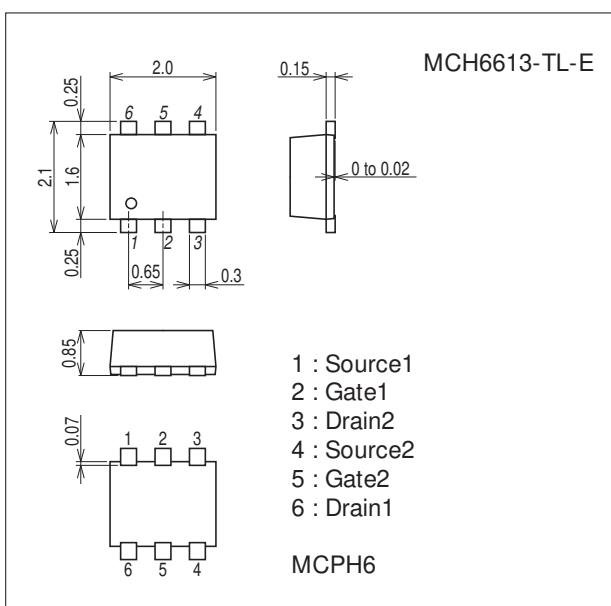
* Machine Model

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

7022A-006

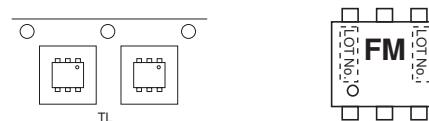


Ordering & Package Information

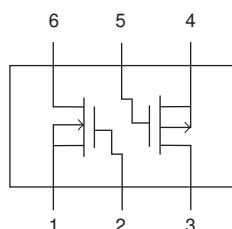
| Device | Package | Shipping | memo |
|--------------|----------------------------------|--------------------|---------|
| MCH6613-TL-E | MCPH6 SC-88, SC-70-6, SOT-363 | 3,000 pcs./reel | Pb-Free |

Packing Type : TL

Marking



Electrical Connection



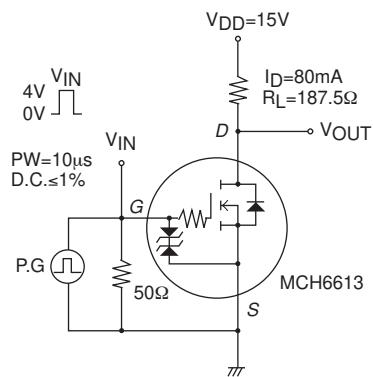
MCH6613

Electrical Characteristics at Ta=25°C

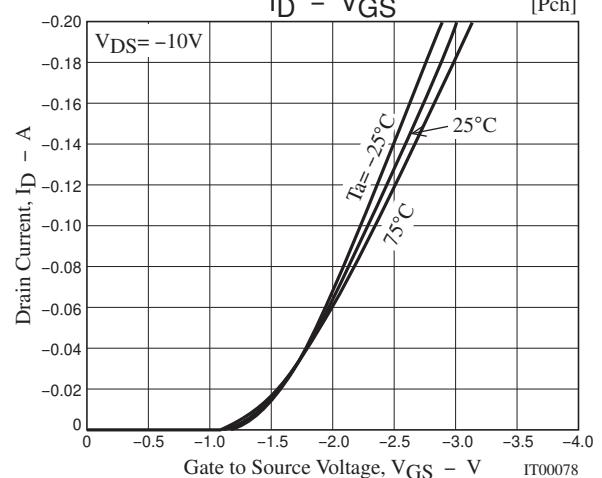
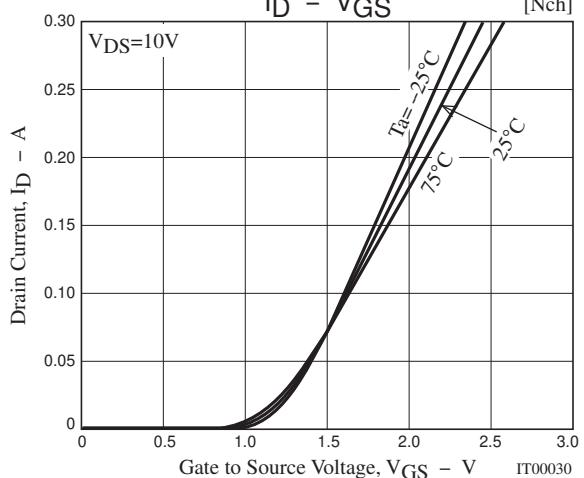
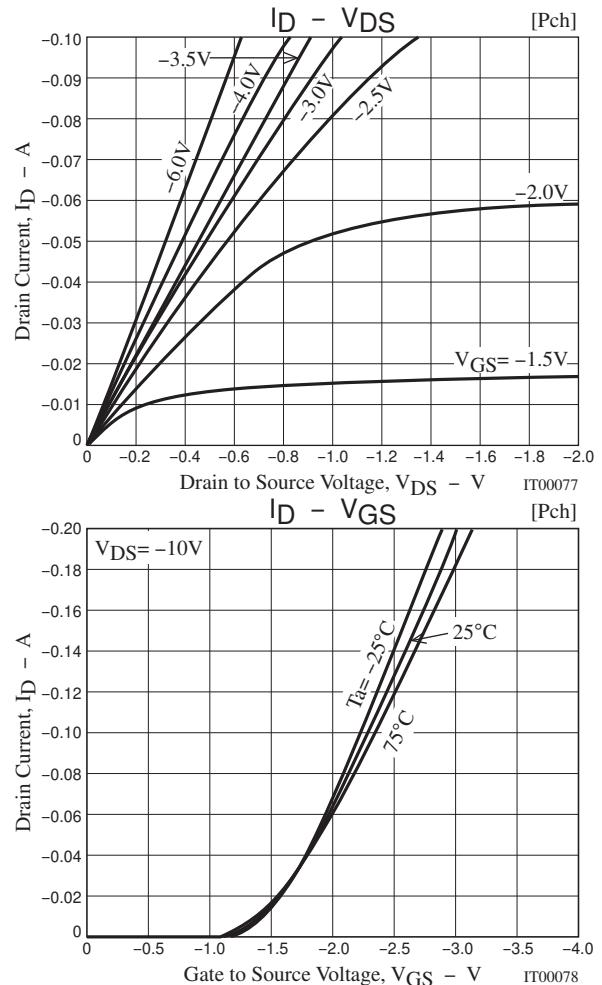
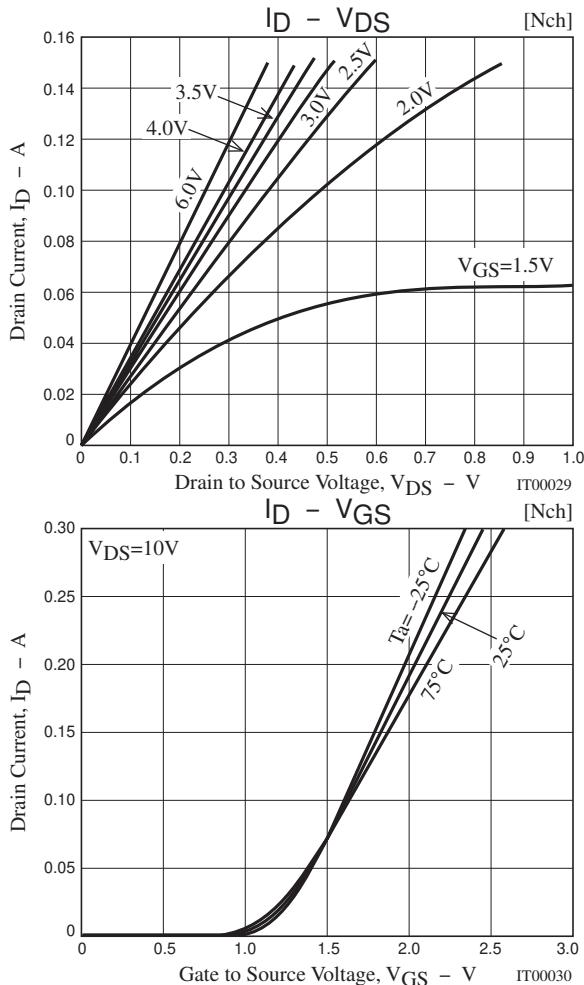
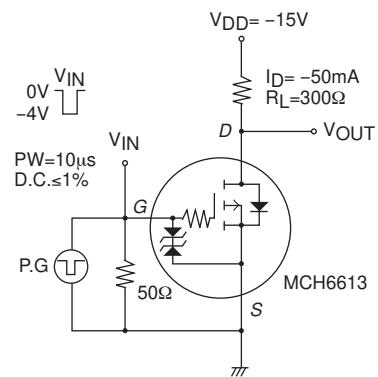
| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|----------|-------------------------------|---------|-------|------|------|
| | | | min | typ | max | |
| [N-channel] | | | | | | |
| Drain to Source Breakdown Voltage | V(BR)DSS | ID=1mA, VGS=0V | 30 | | | V |
| Zero-Gate Voltage Drain Current | IDS | VDS=30V, VGS=0V | | | 1 | μA |
| Gate to Source Leakage Current | IGSS | VGS=±8V, VDS=0V | | | ±10 | μA |
| Cutoff Voltage | VGS(off) | VDS=10V, ID=100μA | 0.4 | | 1.3 | V |
| Forward Transfer Admittance | yfs | VDS=10V, ID=80mA | 150 | 220 | | mS |
| Static Drain to Source On-State Resistance | RDS(on)1 | ID=80mA, VGS=4V | | 2.9 | 3.7 | Ω |
| | RDS(on)2 | ID=40mA, VGS=2.5V | | 3.7 | 5.2 | Ω |
| | RDS(on)3 | ID=10mA, VGS=1.5V | | 6.4 | 12.8 | Ω |
| Input Capacitance | Ciss | | | 7.0 | | pF |
| Output Capacitance | Coss | VDS=10V, f=1MHz | | 5.9 | | pF |
| Reverse Transfer Capacitance | Crss | | | 2.3 | | pF |
| Turn-ON Delay Time | td(on) | | | 19 | | ns |
| Rise Time | tr | See specified Test Circuit. | | 65 | | ns |
| Turn-OFF Delay Time | td(off) | | | 155 | | ns |
| Fall Time | tf | | | 120 | | ns |
| Total Gate Charge | Qg | | | 1.58 | | nC |
| Gate to Source Charge | Qgs | VDS=10V, VGS=10V, ID=150mA | | 0.26 | | nC |
| Gate to Drain "Miller" Charge | Qgd | | | 0.31 | | nC |
| Diode Forward Voltage | VSD | | | 0.87 | 1.2 | V |
| [P-channel] | | | | | | |
| Drain to Source Breakdown Voltage | V(BR)DSS | ID=-1mA, VGS=0V | -30 | | | V |
| Zero-Gate Voltage Drain Current | IDS | VDS=-30V, VGS=0V | | | -1 | μA |
| Gate to Source Leakage Current | IGSS | VGS=±8V, VDS=0V | | | ±10 | μA |
| Cutoff Voltage | VGS(off) | VDS=-10V, ID=-100μA | -0.4 | | -1.4 | V |
| Forward Transfer Admittance | yfs | VDS=-10V, ID=-50mA | 80 | 110 | | mS |
| Static Drain to Source On-State Resistance | RDS(on)1 | ID=-50mA, VGS=-4V | | 8 | 10.4 | Ω |
| | RDS(on)2 | ID=-30mA, VGS=-2.5V | | 11 | 15.4 | Ω |
| | RDS(on)3 | ID=-1mA, VGS=-1.5V | | 27 | 54 | Ω |
| Input Capacitance | Ciss | VDS=-10V, f=1MHz | | 7.5 | | pF |
| Output Capacitance | Coss | | | 5.7 | | pF |
| Reverse Transfer Capacitance | Crss | | | 1.8 | | pF |
| Turn-ON Delay Time | td(on) | See specified Test Circuit. | | 24 | | ns |
| Rise Time | tr | | | 55 | | ns |
| Turn-OFF Delay Time | td(off) | | | 120 | | ns |
| Fall Time | tf | | | 130 | | ns |
| Total Gate Charge | Qg | VDS=-10V, VGS=-10V, ID=-100mA | | 1.43 | | nC |
| Gate to Source Charge | Qgs | | | 0.18 | | nC |
| Gate to Drain "Miller" Charge | Qgd | | | 0.25 | | nC |
| Diode Forward Voltage | VSD | IS=-100mA, VGS=0V | | -0.83 | -1.2 | V |

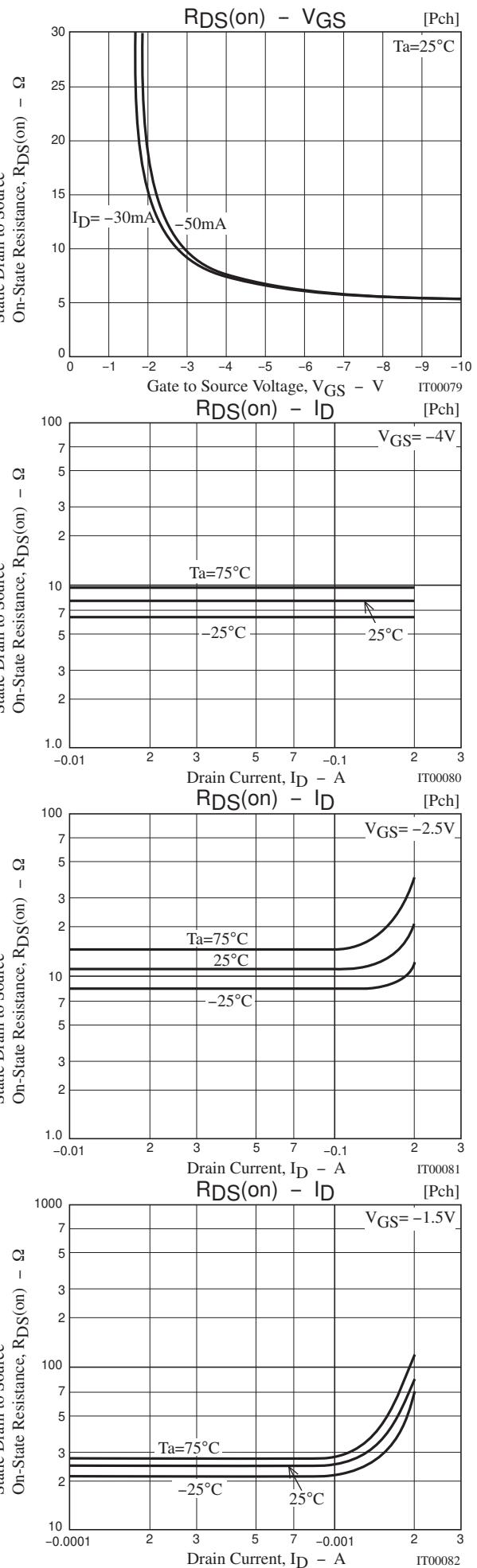
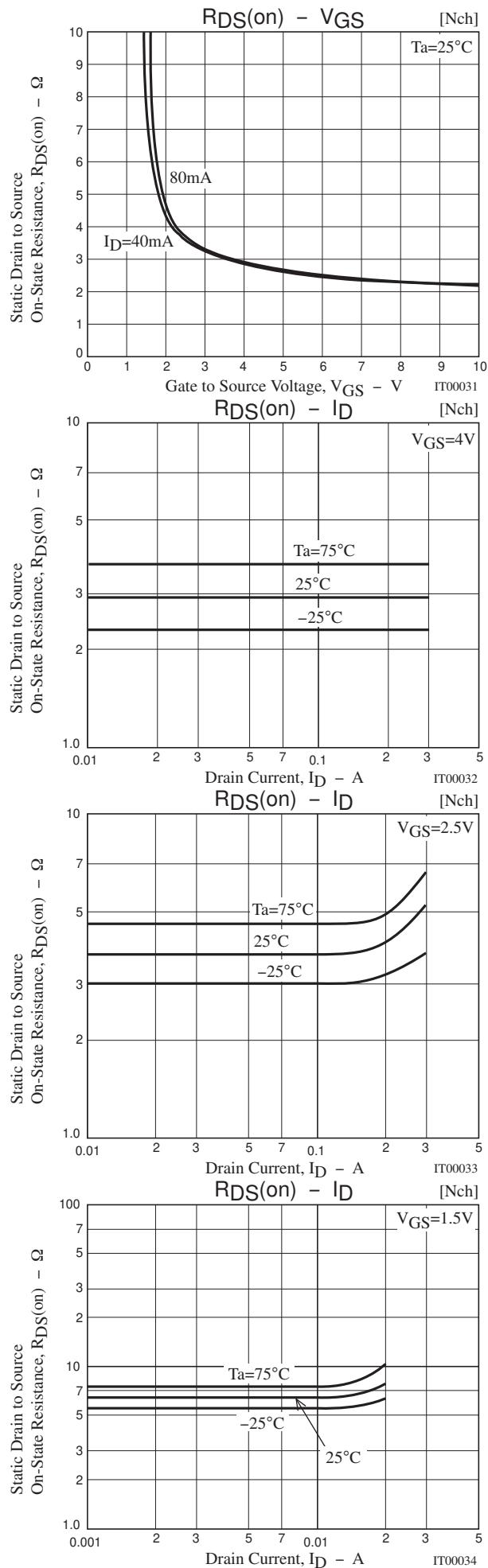
Switching Time Test Circuit

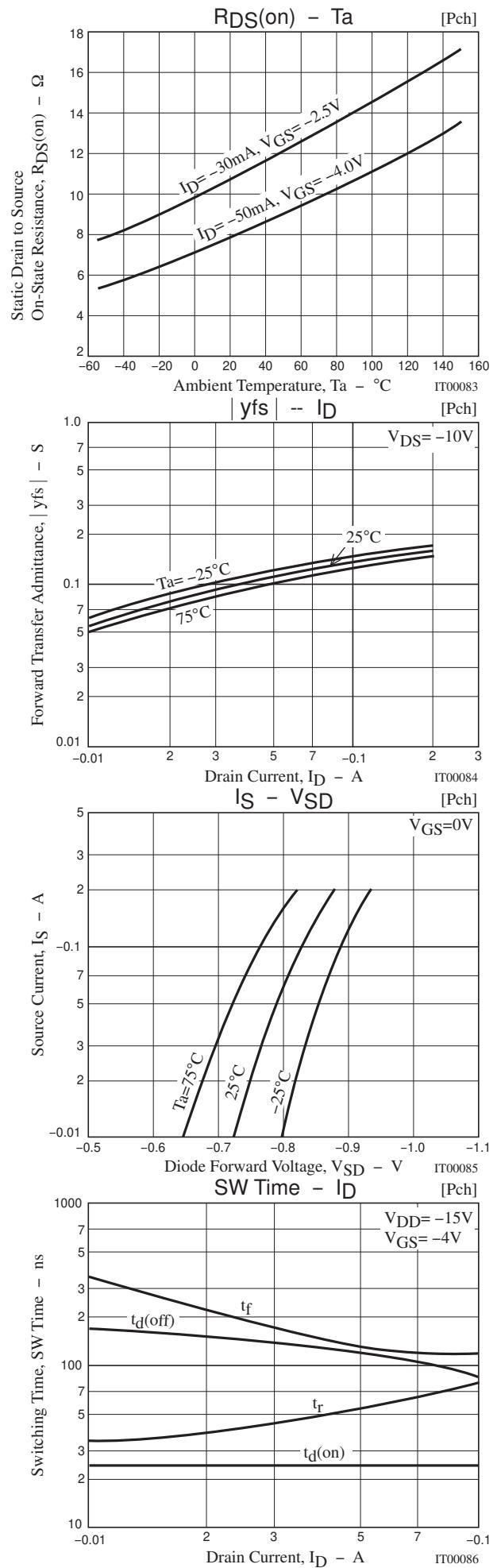
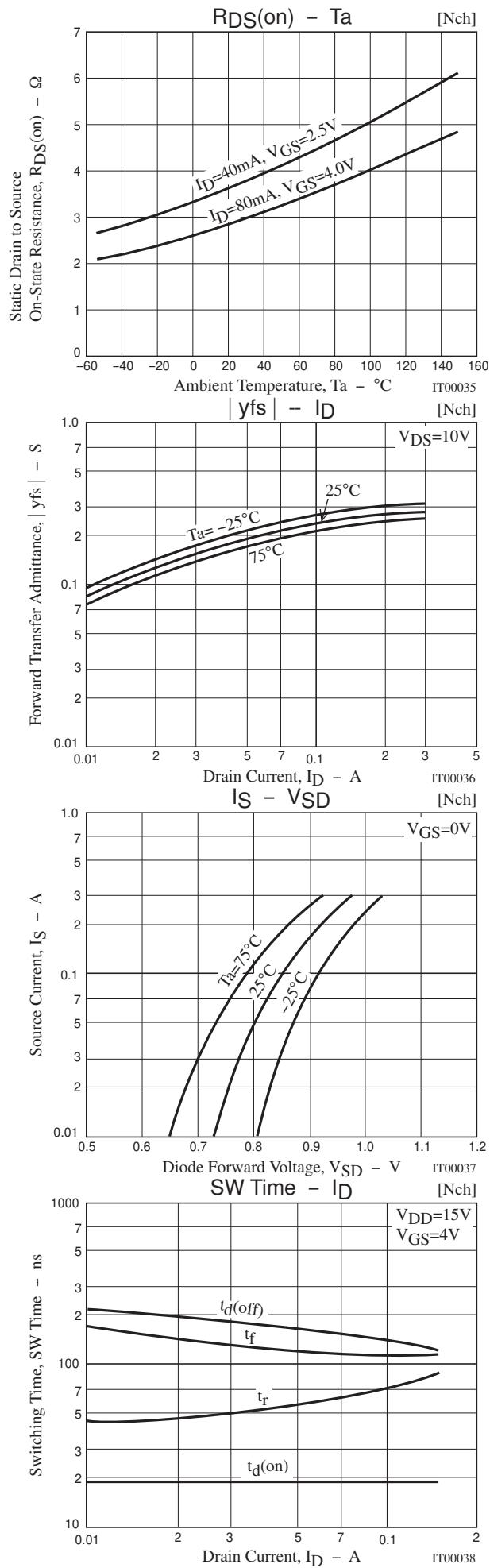
[N-channel]

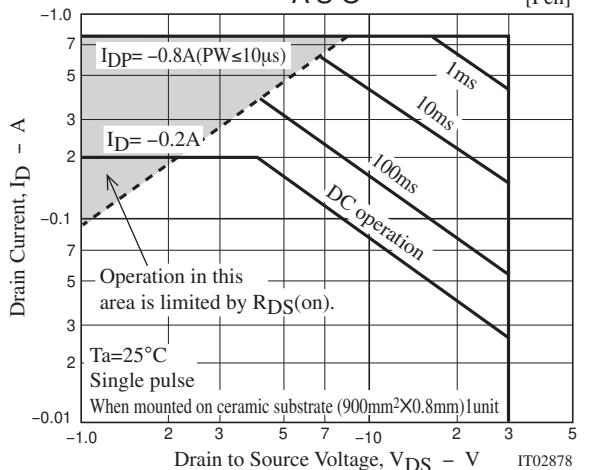
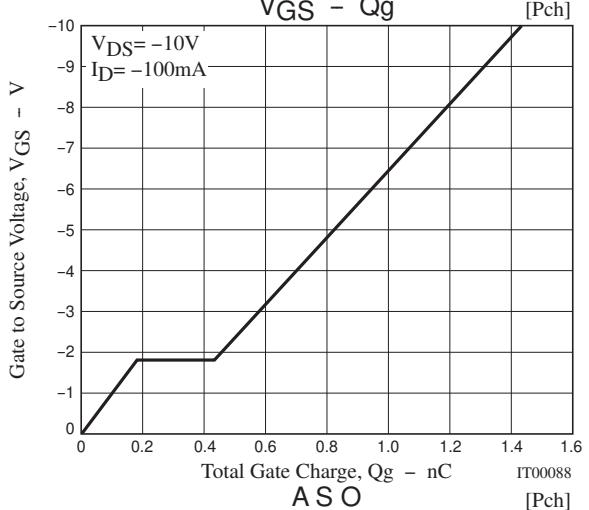
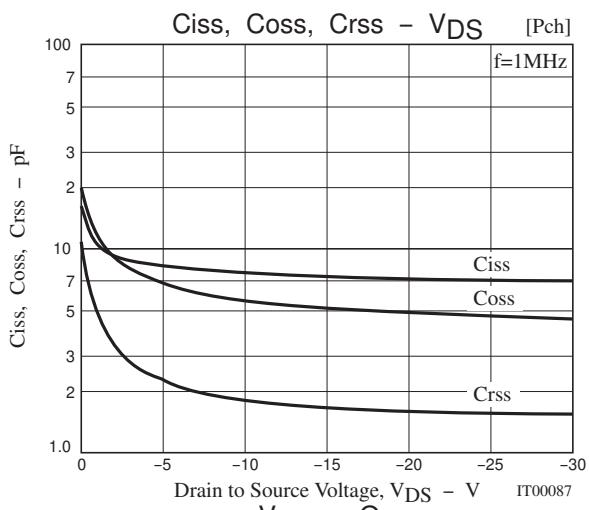
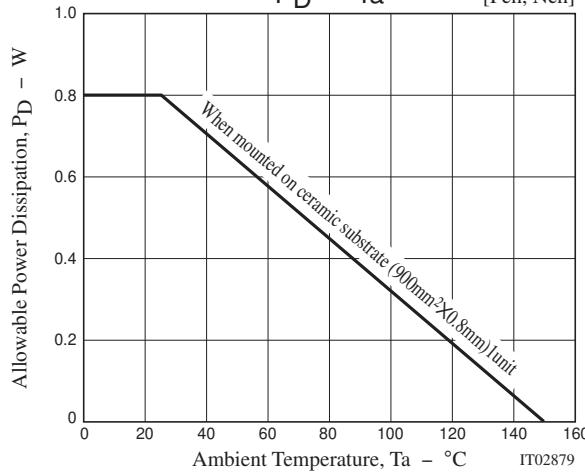
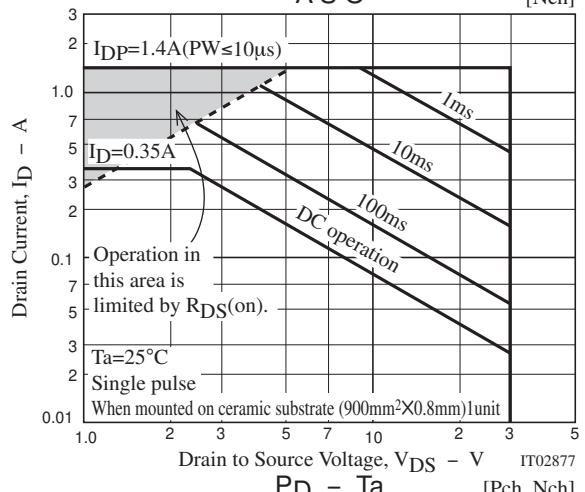
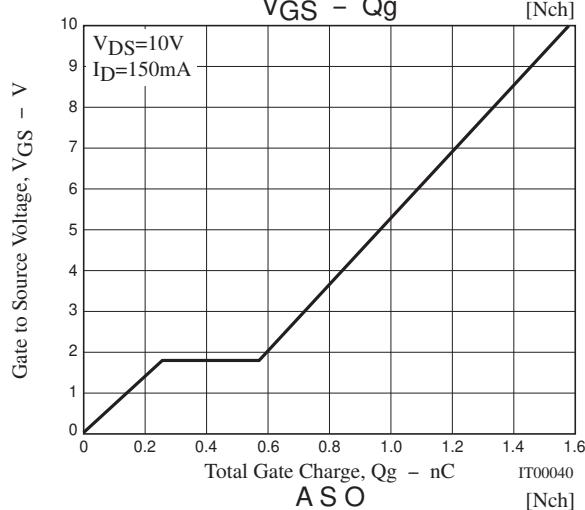
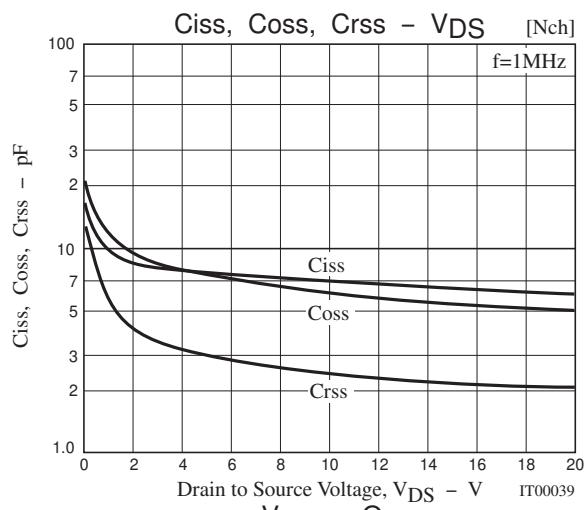


[P-channel]





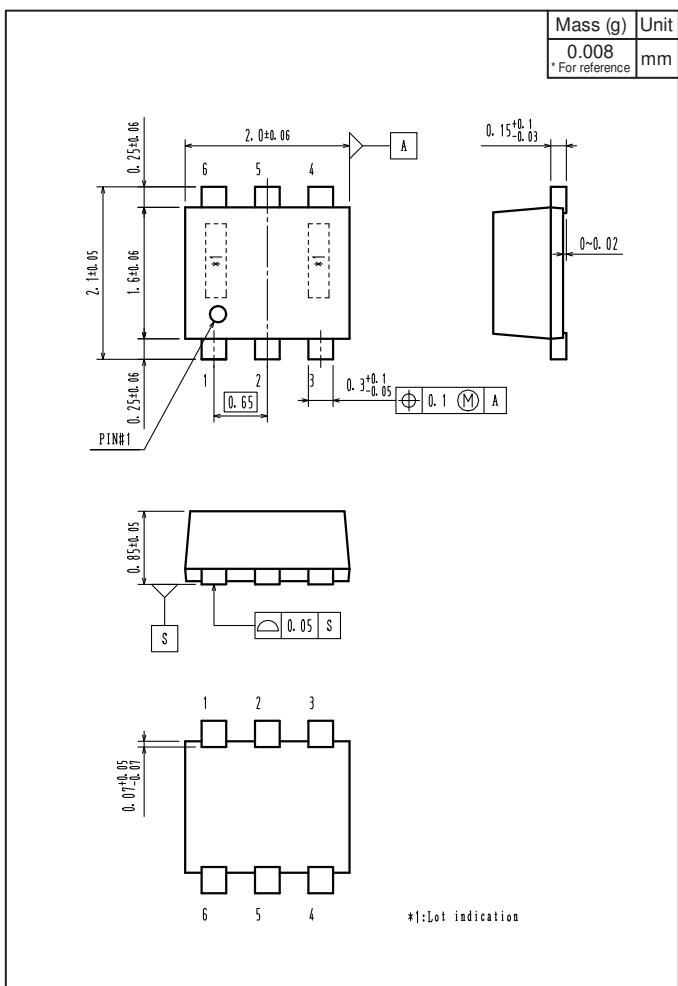




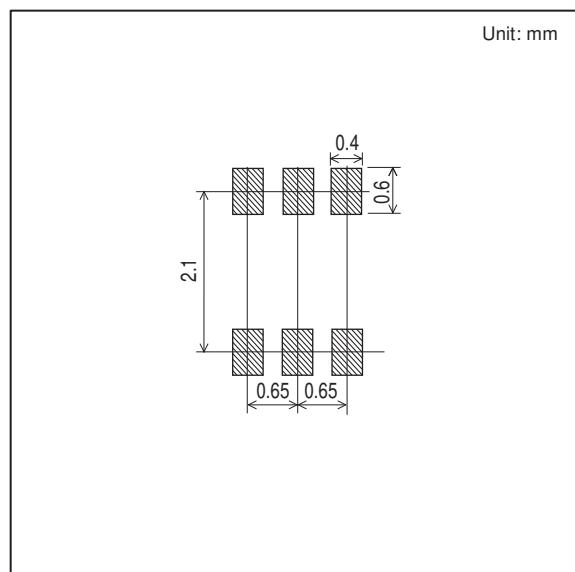
MCH6613

Outline Drawing

MCH6613-TL-E



Land Pattern Example



Note on usage : Since the MCH6613 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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